### 3.3 V ECL Differential Clock D Flip-Flop

## MC100LVEL51

## Description

The MC100LVEL51 is a differential clock D flip-flop with reset. The device is functionally equivalent to the EL51 device, but operates from a 3.3 V supply. With propagation delays and output transition times essentially equal to the EL51, the LVEL51 is ideally suited for those applications which require the ultimate in AC performance at $3.3 \mathrm{~V} \mathrm{~V}_{\mathrm{CC}}$.

The reset input is an asynchronous, level triggered signal. Data enters the master portion of the flip-flop when the clock is LOW and is transferred to the slave, and thus the outputs, upon a positive transition of the clock. The differential clock inputs of the LVEL51 allow the device to be used as a negative edge triggered flip-flop.

The differential input employs clamp circuitry to maintain stability under open input conditions. When left open, the CLK input will be pulled down to $\mathrm{V}_{\mathrm{EE}}$ and the $\overline{\mathrm{CLK}}$ input will be biased at $\mathrm{V}_{\mathrm{CC}} / 2$.

## Features

- 475 ps Propagation Delay
- 2.8 GHz Toggle Frequency
- ESD Protection: $>4$ kV Human Body Model, > 200 V Machine Model
- The 100 Series Contains Temperature Compensation
- PECL Mode Operating Range: $\mathrm{V}_{\mathrm{CC}}=3.0 \mathrm{~V}$ to 3.8 V with $\mathrm{V}_{\mathrm{EE}}=0 \mathrm{~V}$
- NECL Mode Operating Range: $\mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V}$
with $\mathrm{V}_{\mathrm{EE}}=-3.0 \mathrm{~V}$ to -3.8 V
- Internal Input Pulldown Resistors
- Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test
- Moisture Sensitivity Level
- Level 1 for SOIC-8 NB
- Level 3 for TSSOP-8
- For Additional Information, see Application Note AND8003/D
- Flammability Rating: UL 94 V-0 @ 0.125 in, Oxygen Index: 28 to 34
- Transistor Count $=114$ devices
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant

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MARKING DIAGRAMS*


A =Assembly Location
L = Wafer Lot
Y = Year
W = Work Week

- = Pb-Free Package
(Note: Microdot may be in either location)
*For additional marking information, refer to
Application Note AND8002/D.

ORDERING INFORMATION

| Device | Package | Shipping $^{\dagger}$ |
| :---: | :---: | :---: |
| MC100LVEL51DG | SOIC-8 NB <br> (Pb-Free) | 98 Units/Tube |
| MC100LVEL51DTR2G | TSSOP-8 <br> (Pb-Free) | $2500 /$ <br> Tape \& Reel |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.


Figure 1. Logic Diagram and Pinout Assignment

Table 1. PIN DESCRIPTION

| PIN | FUNCTION |
| :--- | :--- |
| CLK, CLK | ECL Differential Clock Input |
| $Q, \bar{Q}$ | ECL Differential Output |
| $D$ | ECL D Input |
| $R$ | ECL Reset Input |
| $V_{\text {CC }}$ | Positive Supp;y |
| $V_{\text {EE }}$ | Negative Supply |

Table 2. TRUTH TABLE

| D | R | CLK | Q |
| :---: | :---: | :---: | :---: |
| L | L | Z | L |
| H | L | Z | H |
| X | H | X | L |

Z = LOW to HIGH Transition
X = Don't Care

Table 3. MAXIMUM RATINGS

| Symbol | Parameter | Condition 1 | Condition 2 | Rating | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{CC}}$ | PECL Mode Power Supply | $\mathrm{V}_{\mathrm{EE}}=0 \mathrm{~V}$ |  | 8 to 0 | V |
| $\mathrm{V}_{\mathrm{EE}}$ | NECL Mode Power Supply | $\mathrm{V}_{\mathrm{CC}}=0 \mathrm{~V}$ |  | -8 to 0 | V |
| $\mathrm{V}_{1}$ | PECL Mode Input Voltage NECL Mode Input Voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{EEE}}=0 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CC}}=0 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{CC}} \\ & \mathrm{~V}_{1} \geq \mathrm{V}_{\mathrm{EE}} \end{aligned}$ | $\begin{gathered} 6 \text { to } 0 \\ -6 \text { to } 0 \end{gathered}$ | V |
| $\mathrm{I}_{\text {out }}$ | Output Current | Continuous Surge |  | $\begin{gathered} 50 \\ 100 \end{gathered}$ | mA |
| $\mathrm{T}_{\mathrm{A}}$ | Operating Temperature Range |  |  | -40 to +85 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ | Storage Temperature Range |  |  | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| $\theta_{\mathrm{JA}}$ | Thermal Resistance (Junction-to-Ambient) | $\begin{aligned} & 0 \text { lfpm } \\ & 500 \text { lfpm } \end{aligned}$ | SOIC-8 NB | $\begin{aligned} & 190 \\ & 130 \end{aligned}$ | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\theta_{\text {Jc }}$ | Thermal Resistance (Junction-to-Case) | Standard Board | SOIC-8 NB | 41 to $44 \pm 5 \%$ | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\theta_{\mathrm{JA}}$ | Thermal Resistance (Junction-to-Ambient) | $\begin{aligned} & \hline 0 \text { lfpm } \\ & 500 \text { lfpm } \end{aligned}$ | TSSOP-8 | $\begin{aligned} & \hline 185 \\ & 140 \end{aligned}$ | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\theta_{\text {Jc }}$ | Thermal Resistance (Junction-to-Case) | Standard Board | TSSOP-8 | 41 to $44 \pm 5 \%$ | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{T}_{\text {sol }}$ | Wave Solder (Pb-Free) | <2 to 3 sec @ $260^{\circ} \mathrm{C}$ |  | 265 | ${ }^{\circ} \mathrm{C}$ |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. JEDEC standard multilayer board - 2S2P (2 signal, 2 power).

Table 4. LVPECL DC CHARACTERISTICS $\left(\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V} ; \mathrm{V}_{\mathrm{EE}}=0.0 \mathrm{~V}\right.$ (Note 1))

| Symbol | Characteristic | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max |  |
| $l_{\text {EE }}$ | Power Supply Current |  | 30 | 35 |  | 30 | 35 |  | 32 | 37 | mA |
| $\mathrm{V}_{\mathrm{OH}}$ | Output HIGH Voltage (Note 2) | 2215 | 2295 | 2420 | 2275 | 2345 | 2420 | 2275 | 2345 | 2420 | mV |
| $\mathrm{V}_{\text {OL }}$ | Output LOW Voltage (Note 2) | 1470 | 1605 | 1745 | 1490 | 1595 | 1680 | 1490 | 1595 | 1680 | mV |
| $\mathrm{V}_{\mathrm{IH}}$ | Input HIGH Voltage (Single-Ended) | 2135 |  | 2420 | 2135 |  | 2420 | 2135 |  | 2420 | mV |
| $\mathrm{V}_{\mathrm{IL}}$ | Input LOW Voltage (Single-Ended) | 1490 |  | 1825 | 1490 |  | 1825 | 1490 |  | 1825 | mV |
| $\mathrm{V}_{\text {IHCMR }}$ | $\begin{aligned} & \text { Input HIGH Voltage Common Mode } \\ & \text { Range (Differential) (Note 3) } \\ & V_{\mathrm{PP}}<500 \mathrm{mV} \text { ) } \\ & \mathrm{V}_{\mathrm{PP}} \geq 500 \mathrm{mV} \end{aligned}$ | $\begin{aligned} & 1.2 \\ & 1.4 \end{aligned}$ |  | $\begin{aligned} & 3.0 \\ & 3.0 \end{aligned}$ | $\begin{aligned} & 1.1 \\ & 1.3 \end{aligned}$ |  | $\begin{aligned} & 3.0 \\ & 3.0 \end{aligned}$ | $\begin{aligned} & 1.1 \\ & 1.3 \end{aligned}$ |  | $\begin{aligned} & 3.0 \\ & 3.0 \end{aligned}$ | V |
| $\mathrm{IIH}^{\text {I }}$ | Input HIGH Current |  |  | 150 |  |  | 150 |  |  | 150 | $\mu \mathrm{A}$ |
| IIL | Input LOW Current Others CLK | $\begin{gathered} 0.5 \\ -600 \end{gathered}$ |  |  | $\begin{gathered} 0.5 \\ -600 \end{gathered}$ |  |  | $\begin{gathered} 0.5 \\ -600 \end{gathered}$ |  |  | $\mu \mathrm{A}$ |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 Ifpm.

1. Input and output parameters vary $1: 1$ with $\mathrm{V}_{\mathrm{CC}}$. $\mathrm{V}_{\mathrm{EE}}$ can vary $\pm 0.3 \mathrm{~V}$.
2. Outputs are terminated through a $50 \Omega$ resistor to $\mathrm{V}_{C C}-2.0 \mathrm{~V}$.
3. $\mathrm{V}_{I H C M R}$ min varies $1: 1$ with $\mathrm{V}_{\mathrm{EE}}$, max varies $1: 1$ with $\mathrm{V}_{\mathrm{CC}}$. The $\mathrm{V}_{\mathrm{IHCMR}}$ range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between $\mathrm{V}_{\mathrm{pp}}$ min and 1 V .

Table 5. LVNECL DC CHARACTERISTICS ( $\mathrm{V}_{\mathrm{CC}}=0.0 \mathrm{~V} ; \mathrm{V}_{\mathrm{EE}}=-3.3 \mathrm{~V}$ (Note 1))

| Symbol | Characteristic | $-40^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max |  |
| $\mathrm{I}_{\text {EE }}$ | Power Supply Current |  | 30 | 35 |  | 30 | 35 |  | 32 | 37 | mA |
| $\mathrm{V}_{\mathrm{OH}}$ | Output HIGH Voltage (Note 2) | -1085 | -1005 | -880 | -1025 | -955 | -880 | -1025 | -955 | -880 | mV |
| $\mathrm{V}_{\text {OL }}$ | Output LOW Voltage (Note 2) | -1830 | -1695 | -1555 | -1810 | -1705 | -1620 | -1810 | -1705 | -1620 | mV |
| $\mathrm{V}_{\mathrm{IH}}$ | Input HIGH Voltage (Single-Ended) | -1165 |  | -880 | -1165 |  | -880 | -1165 |  | -880 | mV |
| $\mathrm{V}_{\text {IL }}$ | Input LOW Voltage (Single-Ended) | -1810 |  | -1475 | -1810 |  | -1475 | -1810 |  | -1475 | mV |
| $\mathrm{V}_{\text {IHCMR }}$ | $\begin{aligned} & \text { Input HIGH Voltage Common Mode } \\ & \text { Range (Differential) (Note 3) } \\ & V_{\mathrm{PP}}<500 \mathrm{mV} \\ & \mathrm{~V}_{\mathrm{PP}} \geq 500 \mathrm{mV} \end{aligned}$ | $\begin{aligned} & -2.1 \\ & -1.9 \end{aligned}$ |  | $\begin{aligned} & -0.3 \\ & -0.3 \end{aligned}$ | $\begin{aligned} & -2.2 \\ & -2.0 \end{aligned}$ |  | $\begin{aligned} & -0.3 \\ & -0.3 \end{aligned}$ | $\begin{aligned} & -2.2 \\ & -2.0 \end{aligned}$ |  | $\begin{aligned} & -0.3 \\ & -0.3 \end{aligned}$ | V |
| $\mathrm{IIH}^{\text {H }}$ | Input HIGH Current |  |  | 150 |  |  | 150 |  |  | 150 | $\mu \mathrm{A}$ |
| IIL | Input LOW Current Others CLK | $\begin{gathered} 0.5 \\ -600 \end{gathered}$ |  |  | $\begin{gathered} 0.5 \\ -600 \end{gathered}$ |  |  | $\begin{gathered} 0.5 \\ -600 \end{gathered}$ |  |  | $\mu \mathrm{A}$ |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 Ifpm.

1. Input and output parameters vary $1: 1$ with $\mathrm{V}_{\mathrm{CC}} . \mathrm{V}_{\mathrm{EE}}$ can vary $\pm 0.3 \mathrm{~V}$.
2. Outputs are terminated through a $50 \Omega$ resistor to $\mathrm{V}_{C C}-2.0 \mathrm{~V}$.
3. $V_{I H C M R}$ min varies $1: 1$ with $V_{E E}$, max varies $1: 1$ with $V_{C C}$. The $V_{I H C M R}$ range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between $\mathrm{V}_{\mathrm{PP}}$ min and 1 V .

Table 6. AC CHARACTERISTICS $\left(\mathrm{V}_{\mathrm{CC}}=3.3 \mathrm{~V} ; \mathrm{V}_{\mathrm{EE}}=0.0 \mathrm{~V}\right.$ or $\mathrm{V}_{\mathrm{CC}}=0.0 \mathrm{~V} ; \mathrm{V}_{E E}=-3.3 \mathrm{~V}$ (Note 1))

| Symbol | Characteristic | -40 ${ }^{\circ} \mathrm{C}$ |  |  | $25^{\circ} \mathrm{C}$ |  |  | $85^{\circ} \mathrm{C}$ |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max |  |
| $\mathrm{f}_{\text {max }}$ | Maximum Toggle Frequency | 2.7 |  |  | 2.8 |  |  | 2.9 |  |  | GHz |
| $\begin{aligned} & \mathrm{t}_{\mathrm{tPLH}} \\ & \mathrm{t}_{\mathrm{PHLL}} \end{aligned}$ | Propagation Delay to Output CLK R | $\begin{aligned} & 330 \\ & 340 \end{aligned}$ | $\begin{aligned} & 465 \\ & 455 \end{aligned}$ | $\begin{aligned} & 510 \\ & 540 \end{aligned}$ | $\begin{aligned} & 340 \\ & 350 \end{aligned}$ | $\begin{aligned} & 475 \\ & 465 \end{aligned}$ | $\begin{aligned} & 520 \\ & 550 \end{aligned}$ | $\begin{aligned} & 370 \\ & 390 \end{aligned}$ | $\begin{aligned} & 530 \\ & 510 \end{aligned}$ | $\begin{aligned} & 550 \\ & 590 \end{aligned}$ | ps |
| ts | Setup Time | 150 | 0 |  | 150 | 0 |  | 150 | 0 |  | ps |
| $\mathrm{t}_{\mathrm{H}}$ | Hold Time | 200 | 100 |  | 200 | 100 |  | 200 | 100 |  | ps |
| $\mathrm{t}_{\mathrm{RR}}$ | Reset Recovery | 350 | 200 |  | 350 | 200 |  | 350 | 200 |  | ps |
| $t_{\text {PW }}$ | ```Minimum Pulse CLK Width Reset``` | $\begin{aligned} & 400 \\ & 500 \end{aligned}$ |  |  | $\begin{aligned} & 400 \\ & 500 \end{aligned}$ |  |  | $\begin{aligned} & 400 \\ & 500 \end{aligned}$ |  |  | ps |
| $\mathrm{t}_{\text {JITTER }}$ | Cycle-to-Cycle Jitter |  | 6.9 |  |  | 7.0 |  |  | 7.1 |  | ps |
| $\mathrm{V}_{\mathrm{PP}}$ | Input Swing (Note 2) | 150 |  | 1000 | 150 |  | 1000 | 150 |  | 1000 | mV |
| $\mathrm{t}_{\mathrm{r}}$ $\mathrm{t}_{\mathrm{f}}$ | $\begin{aligned} & \text { Output Rise/Fall Times Q } \\ & (20 \%-80 \%) \end{aligned}$ | 120 |  | 320 | 120 |  | 320 | 120 |  | 320 | ps |

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm .

1. $V_{E E}$ can vary $\pm 0.3 \mathrm{~V}$.
2. $\mathrm{V}_{\mathrm{PP}}(\mathrm{min})$ is minimum input swing for which $A C$ parameters are guaranteed.


Figure 2. Typical Termination for Output Driver and Device Evaluation (See Application Note AND8020/D - Termination of ECL Logic Devices.)

Resource Reference of Application Notes
AN1405/D - ECL Clock Distribution Techniques
AN1406/D - Designing with PECL (ECL at +5.0 V )
AN1503/D - ECLinPS ${ }^{m}$ I/O SPiCE Modeling Kit
AN1504/D - Metastability and the ECLinPS Family
AN1568/D - Interfacing Between LVDS and ECL
AN1672/D - The ECL Translator Guide
AND8001/D - Odd Number Counters Design
AND8002/D - Marking and Date Codes
AND8020/D - Termination of ECL Logic Devices
AND8066/D - Interfacing with ECLinPS
AND8090/D - AC Characteristics of ECL Devices


SOIC-8 NB
CASE 751-07
ISSUE AK
SCALE 1:1
DATE 16 FEB 2011


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW
7. 751-01 THRU 751-06 AR
STANDARD IS 751-07.

| DIM | MILLIMETERS |  | INCHES |  |
| :---: | :---: | :---: | :---: | :---: |
|  | MIN | MAX | MIN | MAX |
|  | 4.80 | 5.00 | 0.189 | 0.197 |
| B | 3.80 | 4.00 | 0.150 | 0.157 |
| C | 1.35 | 1.75 | 0.053 | 0.069 |
| D | 0.33 | 0.51 | 0.013 | 0.020 |
| G | 1.27 BSC |  | 0.050 BSC |  |
| H | 0.10 | 0.25 | 0.004 | 0.010 |
| J | 0.19 | 0.25 | 0.007 | 0.010 |
| K | 0.40 | 1.27 | 0.016 | 0.050 |
| M | 0 | $0^{\circ}$ | $8^{\circ}$ | 0 |
|  | $\circ$ | 8 |  |  |
| N | 0.25 | 0.50 | 0.010 | 0.020 |
| S | 5.80 | 6.20 | 0.228 | 0.244 |

## GENERIC

MARKING DIAGRAM*



XXXXX = Specific Device Code
A = Assembly Location
L = Wafer Lot
= Year
$\begin{array}{ll}\mathrm{W} & =\text { Work Week } \\ \text { - } & =\text { Pb-Free Package }\end{array}$
*This information is generic. Please refer to device data sheet for actual part marking. $\mathrm{Pb}-\mathrm{Free}$ indicator, " G " or microdot " $\mathrm{=}$ ", may or may not be present. Some products may not follow the Generic Marking.
*For additional information on our $\mathrm{Pb}-$ Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

## STYLES ON PAGE 2

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SOIC-8 NB
CASE 751-07
ISSUE AK
DATE 16 FEB 2011

STYLE

| PIN 1. | EMITTER |
| ---: | :--- |
| 2. | COLLECTOR |
| 3. | COLLECTOR |
| 4. | EMITTER |
| 5. | EMITTER |
| 6. | BASE |
| 7. | BASE |
| 8. | EMITTER |
| STYLE 5: |  |
| PIN 1. | DRAIN |
| 2. | DRAIN |
| 3. | DRAIN |
| 4. | DRAIN |
| 5. | GATE |
| 6. | GATE |
| 7. | SOURCE |
| 8. | SOURCE |

STYLE 9:
PIN 1. EMITTER, COMMON
COLLECTOR, DIE \#1 COLLECTOR, DIE \#2 EMITTER, COMMON EMITTER, COMMON BASE, DIE \#2
BASE, DIE \#1
8. EMITTER, COMMON

STYLE 13:
PIN 1. N.C.
2. SOURCE
3. SOURCE

GATE
DRAIN
DRAIN
DRAIN
8. DRAIN

STYLE 17:
PIN 1. VCC
V2OUT
V10UT
V10UT
TXE
RXE
VEE
7. GND
8. ACC

STYLE 21:
PIN 1. CATHODE 1
2. CATHODE 2
3. CATHODE 3

CATHODE 4
CATHODE 5
6. COMMON ANODE
7. COMMON ANODE
8. CATHODE 6

STYLE 25:
PIN 1. VIN
2. $\mathrm{N} / \mathrm{C}$

REXT
GND
IOUT
IOUT
IOUT
8. IOUT

## STYLE 29

PIN 1. BASE, DIE \#
EMITTER, \#1
BASE, \#2
. EMITTER, \#2
5. COLLECTOR, \#2
6. COLLECTOR, \#2
7. COLLECTOR, \#1
8. COLLECTOR, \#1

STYLE
PIN 1. COLIECTOR,
2. COLLECTOR, \#
3. COLLECTOR, \#2

COLLECTOR, \#2
BASE, \#2
. EMITTER, \#2
7. BASE, \#1
8. EMITTER, \#1

STYLE 6:
PIN 1. SOURCE
DRAIN
3. DRAIN
4. SOURCE

SOURCE
6. GATE
7. GATE
8. SOURCE

STYLE 10:
PIN 1. GROUND
2. BIAS 1
3. OUTPUT

GROUND
GROUND
BIAS 2
7. INPUT
8. GROUND

STYLE 14
PIN 1. N-SOURCE
2. N-GATE
. P-SOURCE
P-GATE
5.DRAIN
6. P-DRAIN
7. N-DRAIN
8. N -DRAIN

STYLE 18
PIN 1. ANODE
2. ANODE
3. SOURCE
4. GATE
5. DRAIN
6. DRAIN
7. CATHODE
8. CATHODE

STYLE 22 :
PIN 1. I/O LINE
2. COMMON CATHODE/VCC
3. COMMON CATHODE/VCC
4. I/O LINE 3
5. COMMON ANODE/GND
6. I/O LINE 4
7. I/O LINE 5
8. COMMON ANODE/GND

STYLE 26:
PIN 1. GND
2. $\mathrm{dv} / \mathrm{dt}$
3. ENABLE
4. ILIMIT

SOURCE
SOURCE
SOURCE
8. VCC

STYLE 30:
PIN 1. DRAIN 1
2. DRAIN 1
. GATE 2
4. SOURCE 2
5. SOURCE 1/DRAIN 2
. SOURCE 1/DRAIN 2
SOURCE 1/DRAIN 2
8. GATE 1

STYLE 3
STYLE
2. DRAIN, DIE
2. DRAIN, \#1
2. DRAIN, \#
3. DRAIN, \#2
4. DRAIN, \#2
5. GATE, \#2
7. GATE, \#1
8. SOURCE, \#1

## STYLE 7

PIN 1. INPUT
2. EXTERNAL BYPASS
3. THIRD STAGE SOURCE
4. GROUND
5. DRAIN
6. GATE 3
7. SECOND STAGE Vd
8. FIRST STAGE Vd

## STYLE 11:

PIN 1. SOURCE
2. GATE 1
3. SOURCE 2
4. GATE 2
5. DRAIN 2
6. DRAIN 2
7. DRAIN 1
8. DRAIN 1

## STYLE 15:

PIN 1. ANODE 1
2. ANODE 1
3. ANODE 1
4. ANODE 1
5. CATHODE, COMMON
6. CATHODE, COMMON
7. CATHODE, COMMON
8. CATHODE, COMMON

## STYLE 19:

PIN 1. SOURCE
2. GATE 1
3. SOURCE 2
4. GATE 2
5. DRAIN
6. MIRROR 2
7. DRAIN 1
8. MIRROR 1

## STYLE 23:

PIN 1. LINE 1 IN
2. COMMON ANODE/GND
3. COMMON ANODE/GND
4. LINE 2 IN
5. LINE 2 OUT
6. COMMON ANODE/GND
7. COMMON ANODE/GND
8. LINE 1 OUT

STYLE 27:
PIN 1. ILIMIT
2. OVLO
3. UVLO
4. INPUT+
5. INPUT+
5. SOURCE
6. SOURCE
7. SOURCE
8. DRAIN

STYLE 4:
PIN 1. ANODE
2. ANODE
3. ANODE
4. ANODE
5. ANODE
6. ANODE
8. COMMON CATHODE

## STYLE 8:

PIN 1. COLLECTOR, DIE \#1
2. BASE, \#1
3. BASE, \#2
4. COLLECTOR, \#2
5. COLLECTOR, \#2
6. EMITTER, \#2
7. EMITTER, \#1
8. COLLECTOR, \#1

## STYLE 12

PIN 1. SOURCE
2. SOURCE
3. SOURCE
4. GATE
5. DRAIN
6. DRAIN
7. DRAIN
8. DRAIN

## STYLE 16:

PIN 1. EMITTER, DIE \#1
2. BASE, DIE \#1
3. EMITTER, DIE \#2
3. EMITTER, DIE
4. BASE, DIE \#2
4. BASE, DIE \#2
6. COLLECTOR, DIE \#2
7. COLLECTOR, DIE \#1
8. COLLECTOR, DIE \#1

## STYLE 20:

PIN 1. SOURCE (N)
2. GATE (N)
3. SOURCE (P)
4. GATE (P)
5. DRAIN
6. DRAIN
7. DRAIN
8. DRAIN

STYLE 24
PIN 1. BASE
2. EMITTER
3. COLLECTOR/ANODE
4. COLLECTOR/ANODE
5. CATHODE
6. CATHODE
7. COLLECTOR/ANODE
8. COLLECTOR/ANODE

## STYLE 28:

PIN 1. SW_TO_GND
2. DASIC $\bar{O} F F$
3. DASIC_SW_DET
4. GND
5. V_MON
6. VBULK
7. VBULK
8. VIN

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TSSOP 8

## CASE 948R-02

ISSUE A
DATE 04/07/2000

## SCALE 2:1


notes:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PROTRUSI
PER SIDE
5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY
6. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-

|  | MILLIMETERS |  | INCHES |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| DIM | MIN | MAX | MIN | MAX |  |  |
| A | 2.90 | 3.10 | 0.114 | 0.122 |  |  |
| B | 2.90 | 3.10 | 0.114 | 0.122 |  |  |
| C | 0.80 | 1.10 | 0.031 | 0.043 |  |  |
| D | 0.05 | 0.15 | 0.002 | 0.006 |  |  |
| F | 0.40 | 0.70 | 0.016 | 0.028 |  |  |
| G | 0.65 BSC |  | 0.026 BSC |  |  |  |
| K | 0.25 |  | 0.40 | 0.010 |  | 0.016 |
| L | 4.90 BSC |  | 0.193 BSC |  |  |  |
| M | $0^{\circ}$ |  | $6^{\circ}$ | $0^{\circ}$ |  | $6^{\circ}$ |


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| DESCRIPTION: | TSSOP 8 | PAGE 1 OF 1 |

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